



THE PROGRESS OF SIPM-BASED CAMERA FOR LHAASO-WFCTA

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for the LHAASO Collaboration



Outline

- Introduction
 - LHAASO-WFCTA
 - Why SiPM?
- Progress
 - Design of Camera/Sub-Cluster
 - Design of SiPM
 - Pre-amplifier
 - Analog & Digital Board
 - Slow Control Board
 - Winston Cone
- Summary

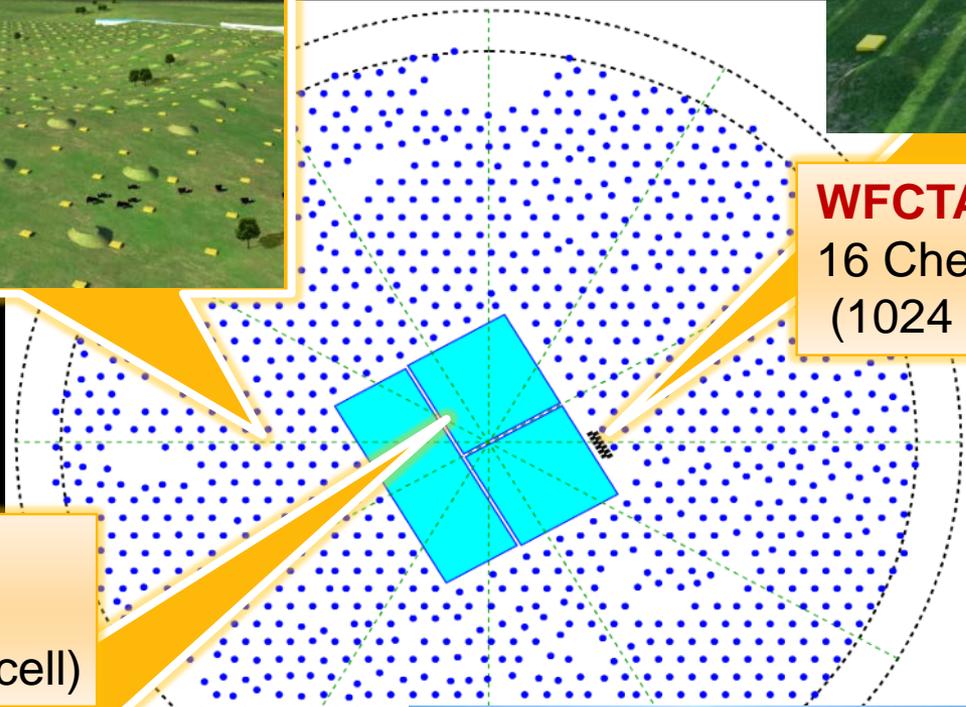
LHAASO



WFCTA:
16 Cherenkov telescopes
(1024 pixels/telescope)

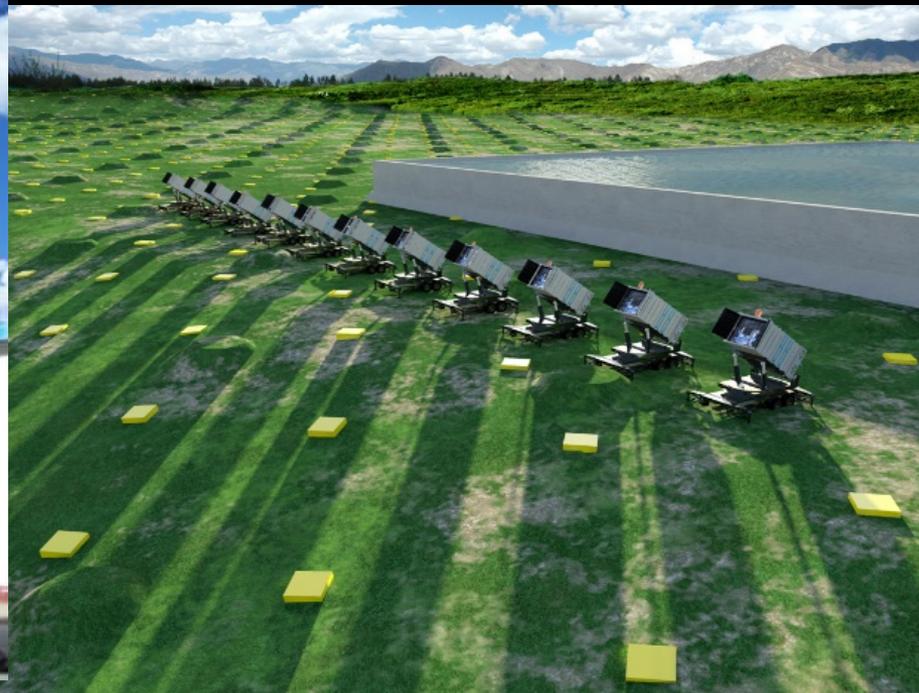
KM2A:
5195 EDs
1171 MDs

WCDA:
78,000 m²
3000 cells(25m²/cell)



Mount. Haizi, Daochen, Sichuan
(29°21' 31" N, 100°08'15" E, 4410 m a.s.l.,
600 g/cm)

WFCTA



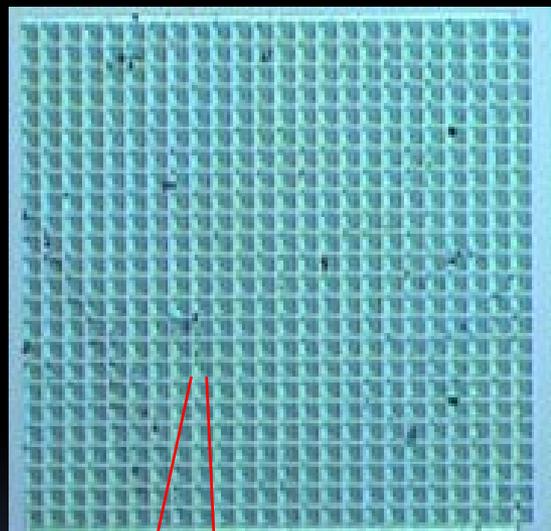
Prototype
16x16 Pixels
1° /pixel
PMT Array



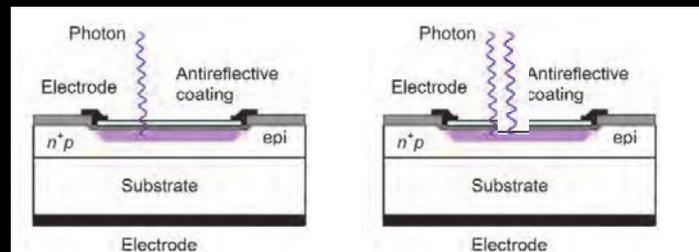
LHAASO-WFCTA
32x32 Pixels
0.5° /pixel
SiPM Array

Introduction to SiPM

- Silicon Photomultiplier
- Geiger mode APD (binary)

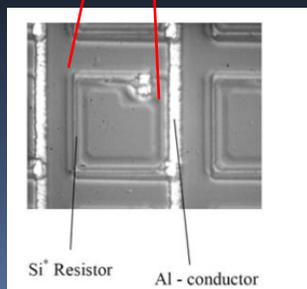


SiPM
1~5mm



Same Output

$$\begin{aligned}
 N_{fired} &= N_{cell} \left(1 - e^{-\epsilon N_{ph}/N_{cell}} \right) \\
 &= N_{cell} \left(1 - e^{-N_{pe}/N_{cell}} \right)
 \end{aligned}$$



APD
20~100μm

PMT vs SiPM

	PMT (WFCTA)	SiPM
Size	✓ 1 inch (25.4mm)	15mm x 15mm
Resolution	12%@100pe, 4%@1000pe	12%@100pe, 4%@1000pe
FWHM of Pulse	~6ns	✓ ~60ns
Dark count rate(Dark noise)	✓ <1kHz @ Th=0.5pe	>10kHz @ Th=0.5pe
Gain	10^6 @ >1000V	✓ 10^6 @ <100V
G-T Stability	✓ ~0.2%/°C	1.5%/°C
Magnetic field	Sensitive	✓ Not sensitive
Ageing under strong light	Yes	✓ No
Dynamic range	Depend on PMT type, HV....	Depend on number of APDs

Why SiPM?

- ✓ High gain at low operating voltage
- ✓ Duty cycle up to 30% (10% for PMT)
- ✓ Experience of FACT & CTA



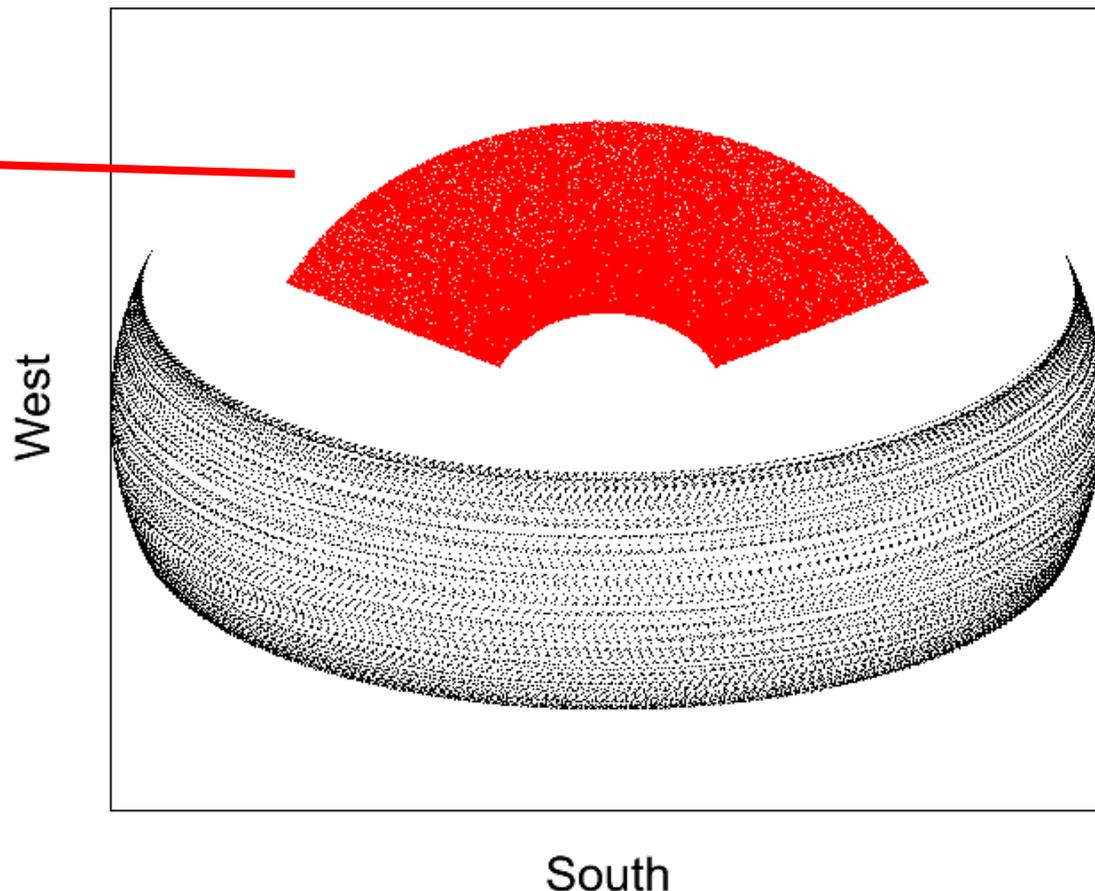
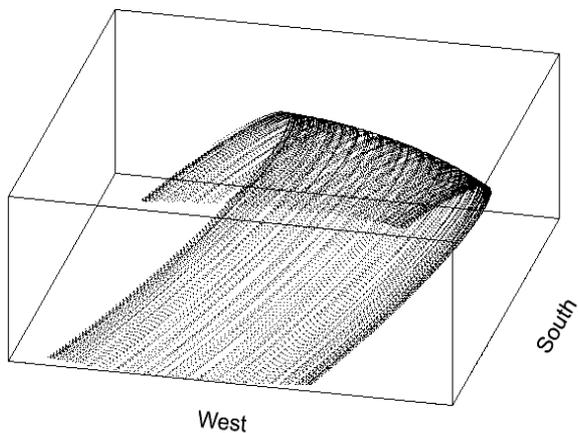
The First G-APD Cherenkov
Telescope (FACT)
La Palma, Canary Islands, Spain,
2011



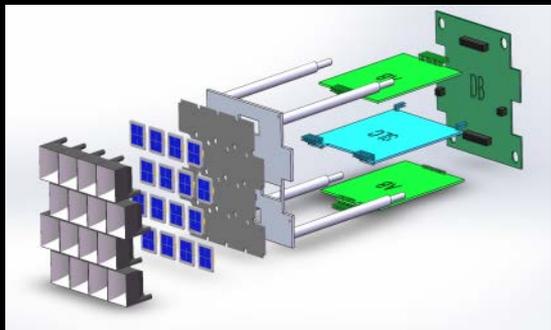
CTA: single-mirror (dual mirror)
Small Size Telescope (High Energy)

Moon trajectory

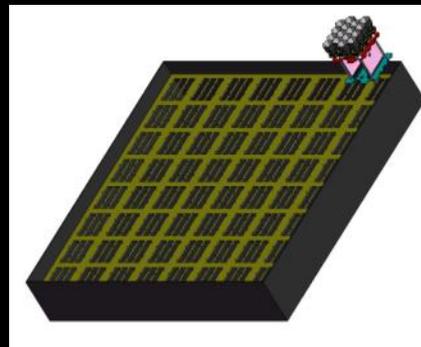
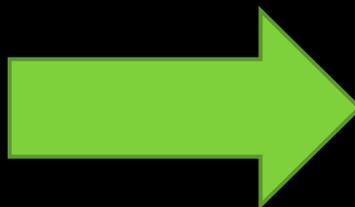
8x2 Telescopes
 $128^\circ \times 32^\circ$
 $90^\circ \pm 64^\circ, 30^\circ \pm 16^\circ$



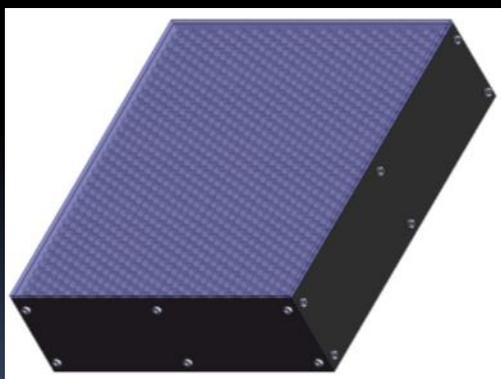
Design of Camera



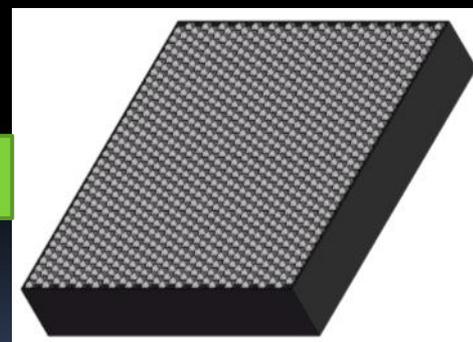
Sub-Cluster:
4x4 SiPM array



Camera
Box

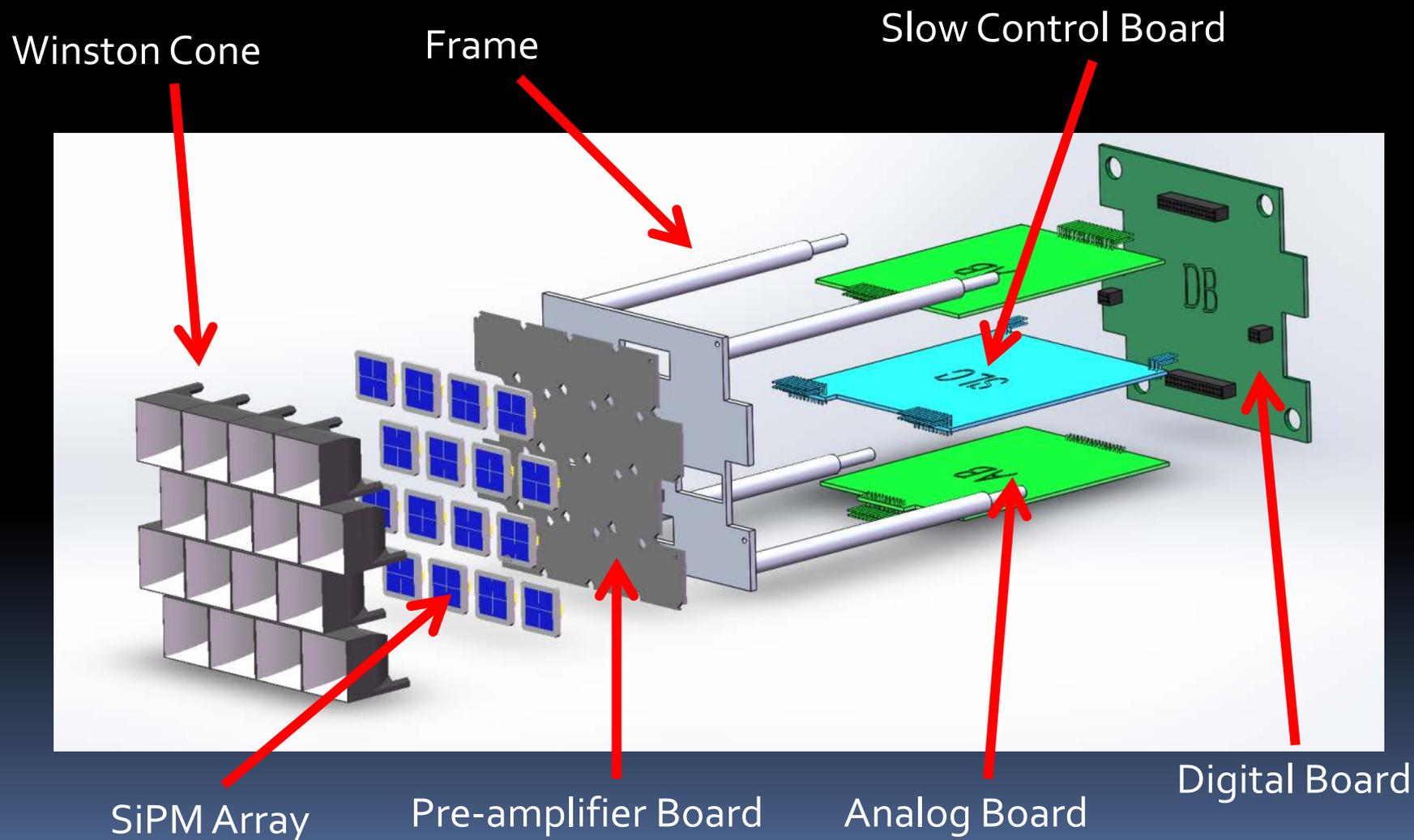


Optical Filter

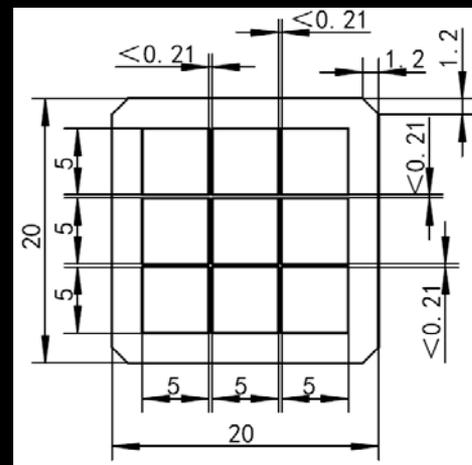
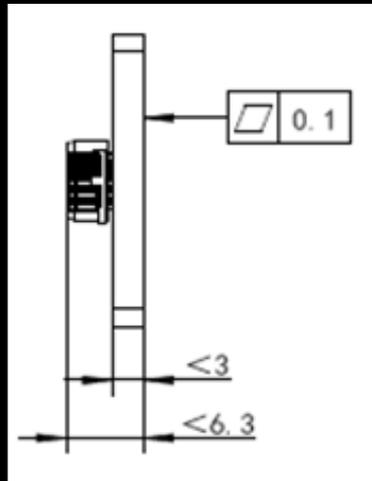
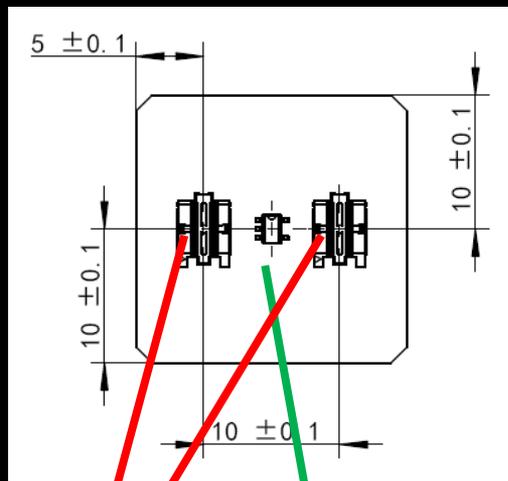


Camera:
8x8 Sub-Clusters

Design of Sub-Cluster



Design of SiPM



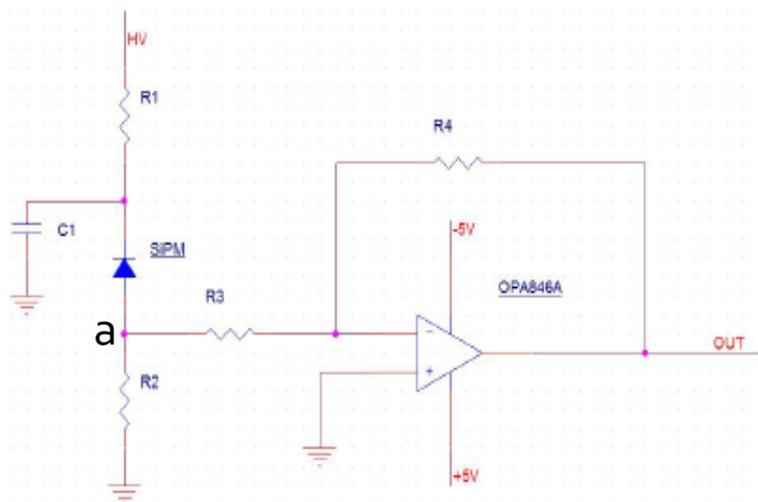
Two
Terminal
Strips

Temperature Sensor
LM94021

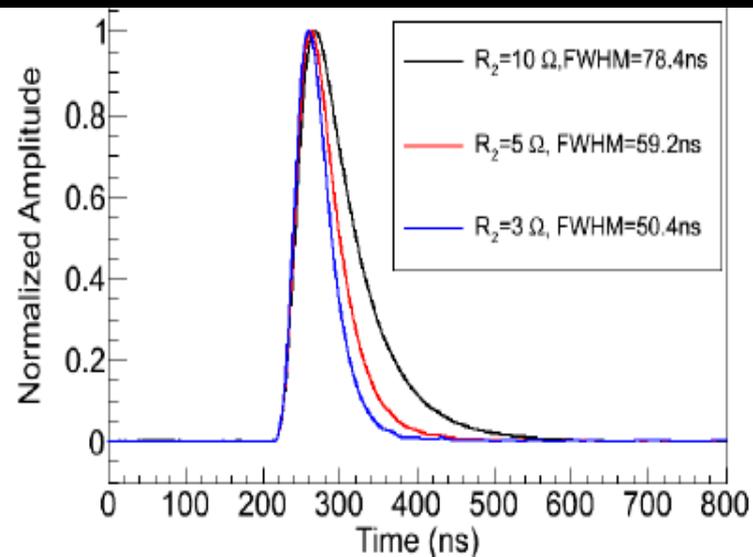
Test Sample:
Hamamatsu S13361-5488
16 (4x4) chips
3mm x 3mm per chip
Pixel Size: 25 μ m x 25 μ m

- Hamamatsu
- 9 (3x3) chips (15mm x 15mm)
- 5mm x 5mm per chip
- Pixel size: 25 μ m x 25 μ m
- Gain=1.1x10⁶ @~60V
- Gain Uniformity: Typ:1.3%
- Dark Count Rate = Typ:5.4Mhz
- V-T Coefficient: 54mV/°C

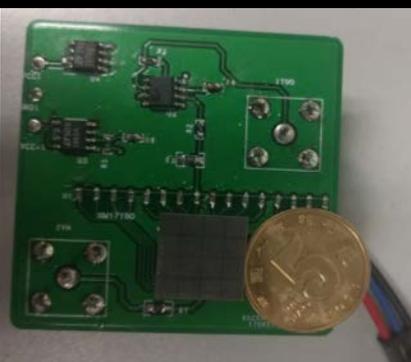
Pre-amplifier



(a)



(b)



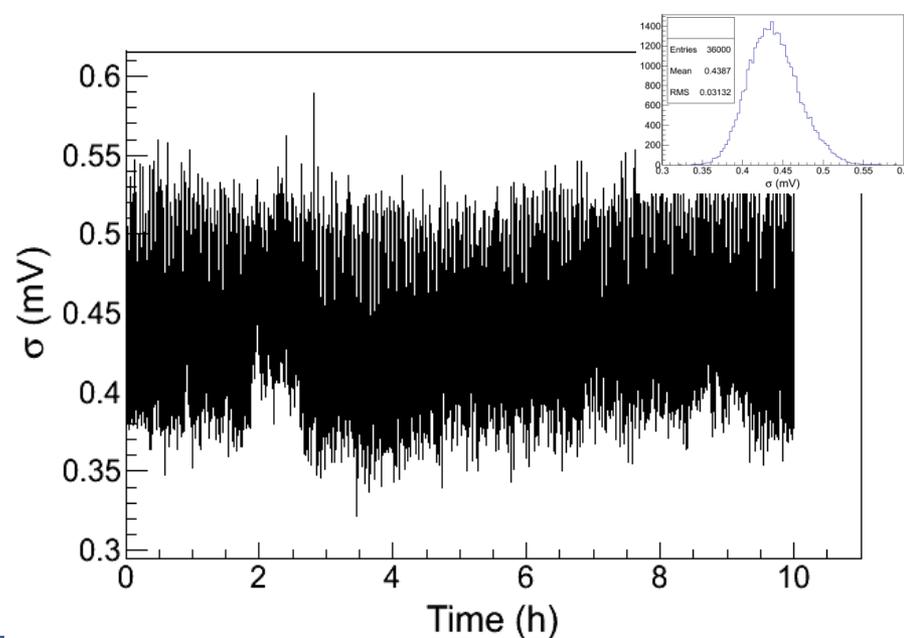
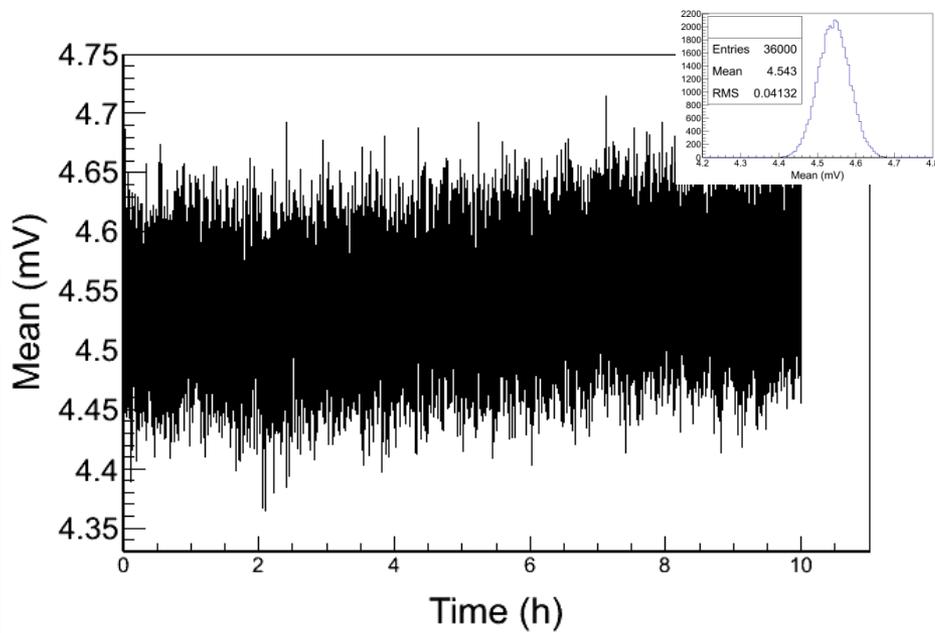
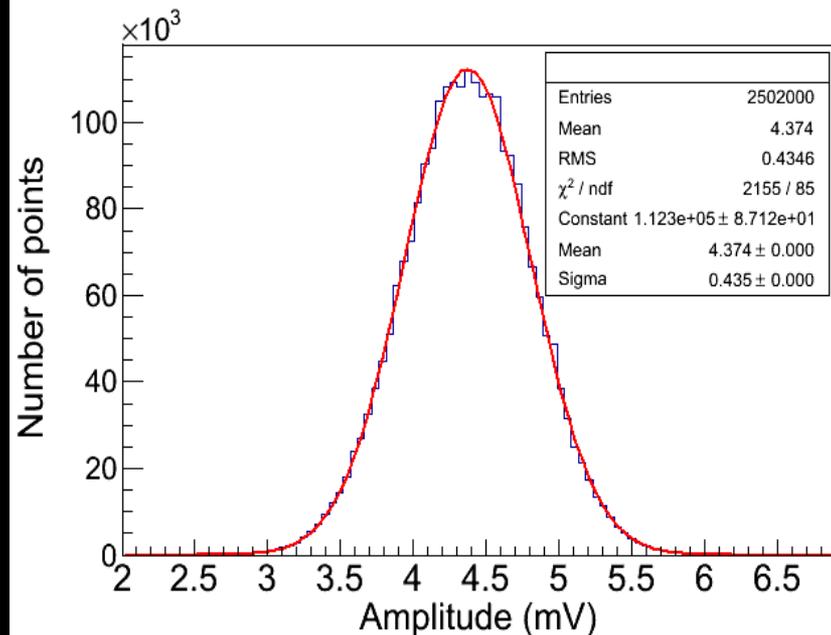
$$R_2 = 3\Omega, \quad R_3 = 100\Omega, \quad R_4 = 1k\Omega$$

$$V_a = I \times 3\Omega$$

Inverting Amplifier: Gain = -10

Pedestal

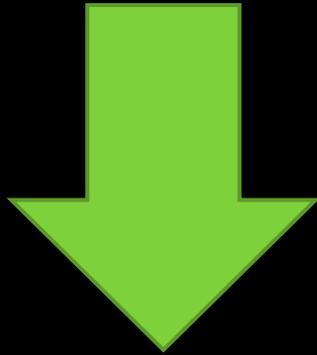
Ped $< 5\text{mV}$
 $\sigma \sim 0.43\text{mV}$



Dynamic ranges

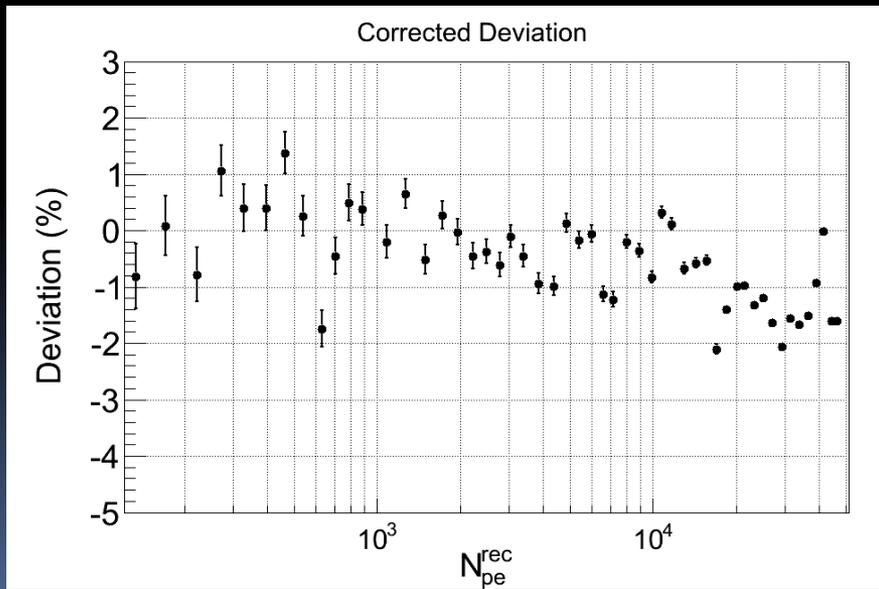
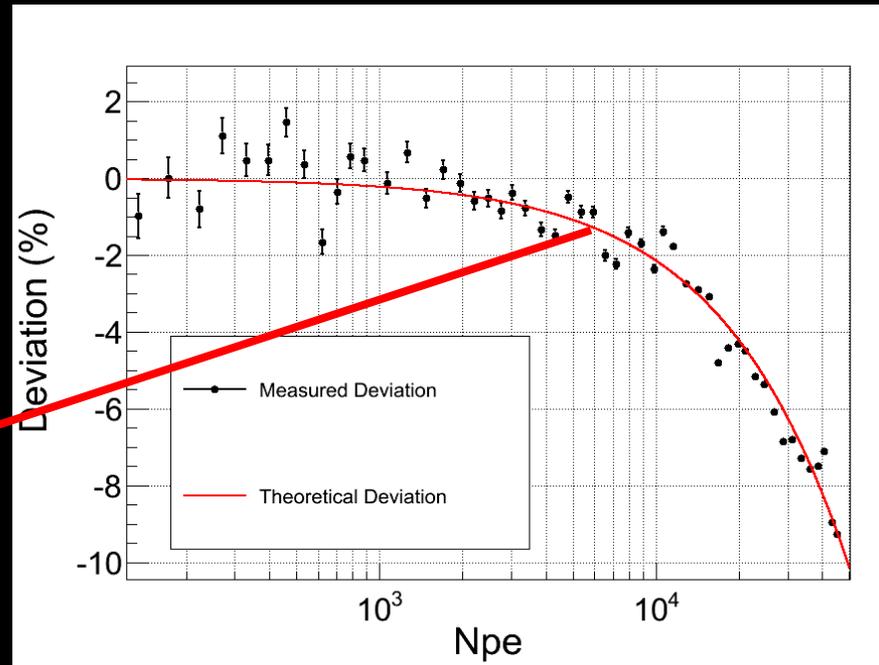
$$N_{fired} = N_{cell} (1 - e^{-\epsilon N_{ph}/N_{cell}})$$

$$= N_{cell} (1 - e^{-N_{pe}/N_{cell}})$$

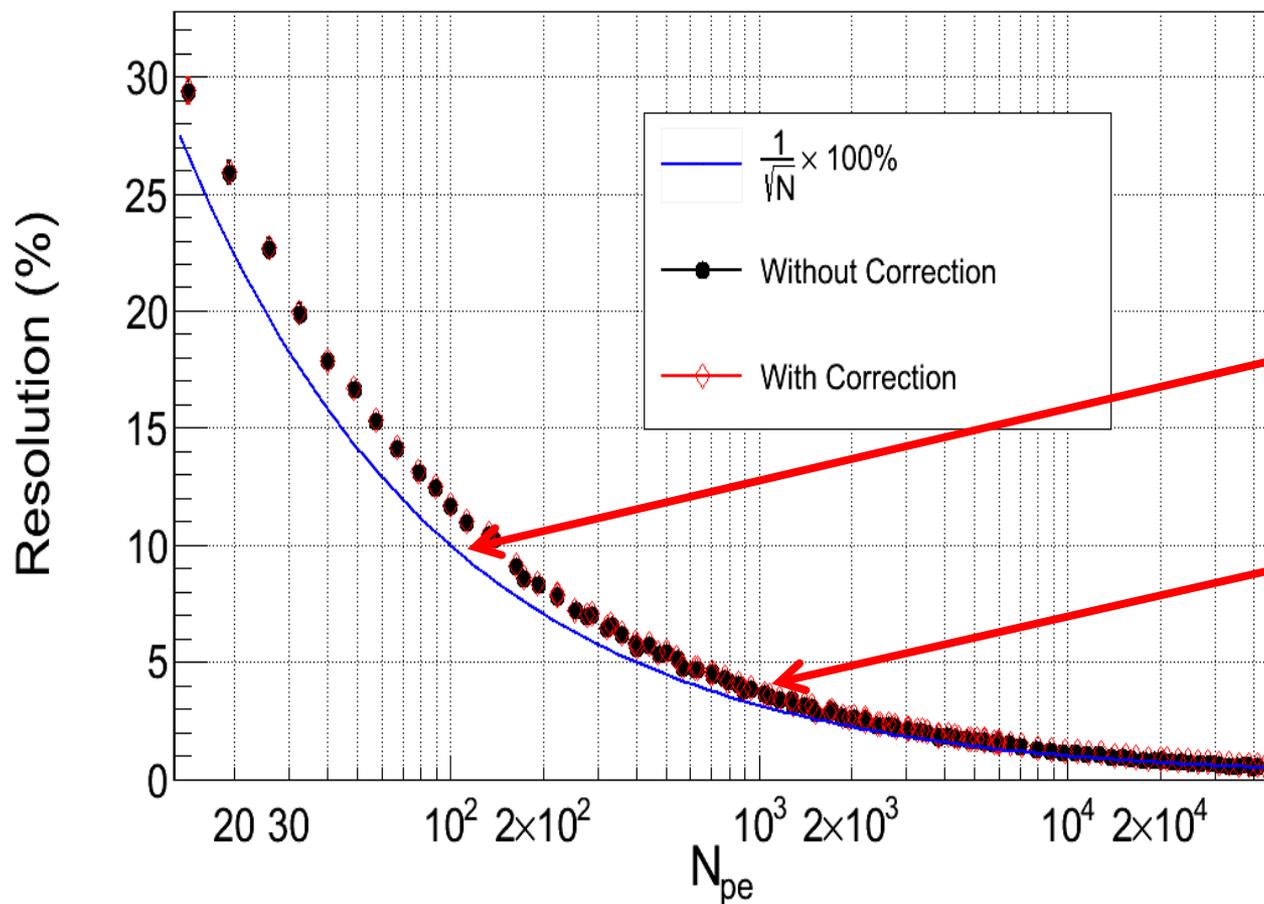


$$N_{pe}^{rec} = N_{cell} \ln\left(\frac{1}{1 - N_{fired}/N_{cell}}\right)$$

Deviation < $\pm 2\%$
up to 50000 pe



Resolution

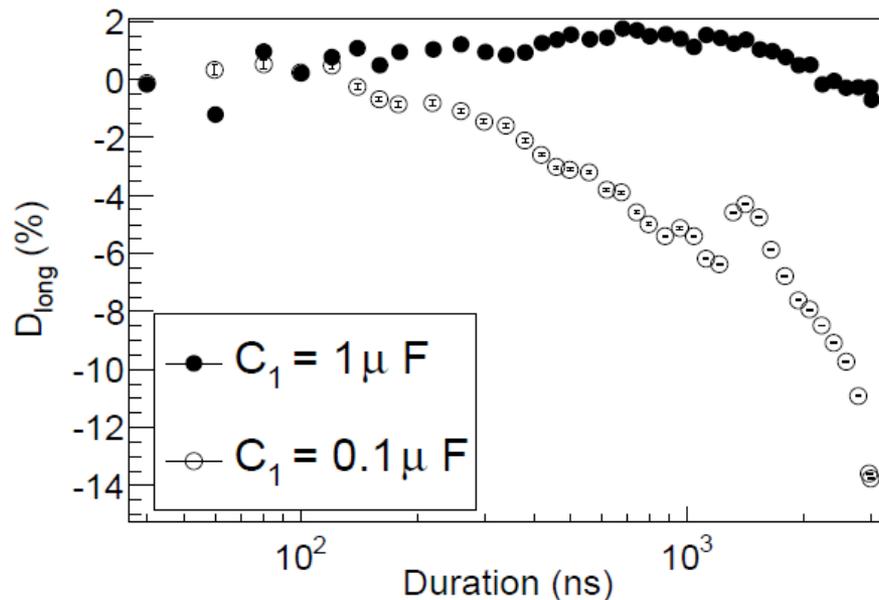
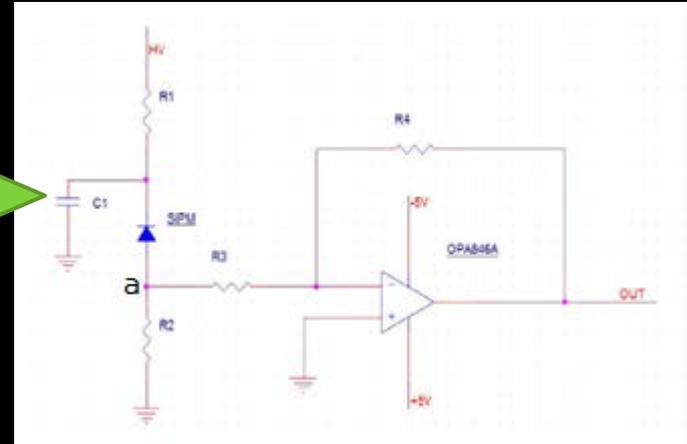


~12%
@100pe

~4%
@1000pe

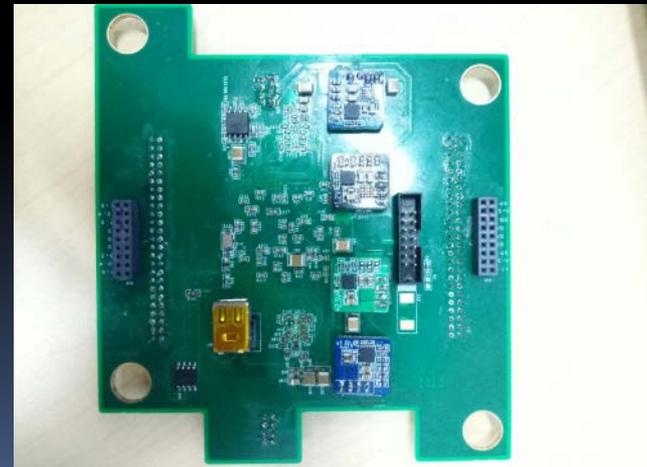
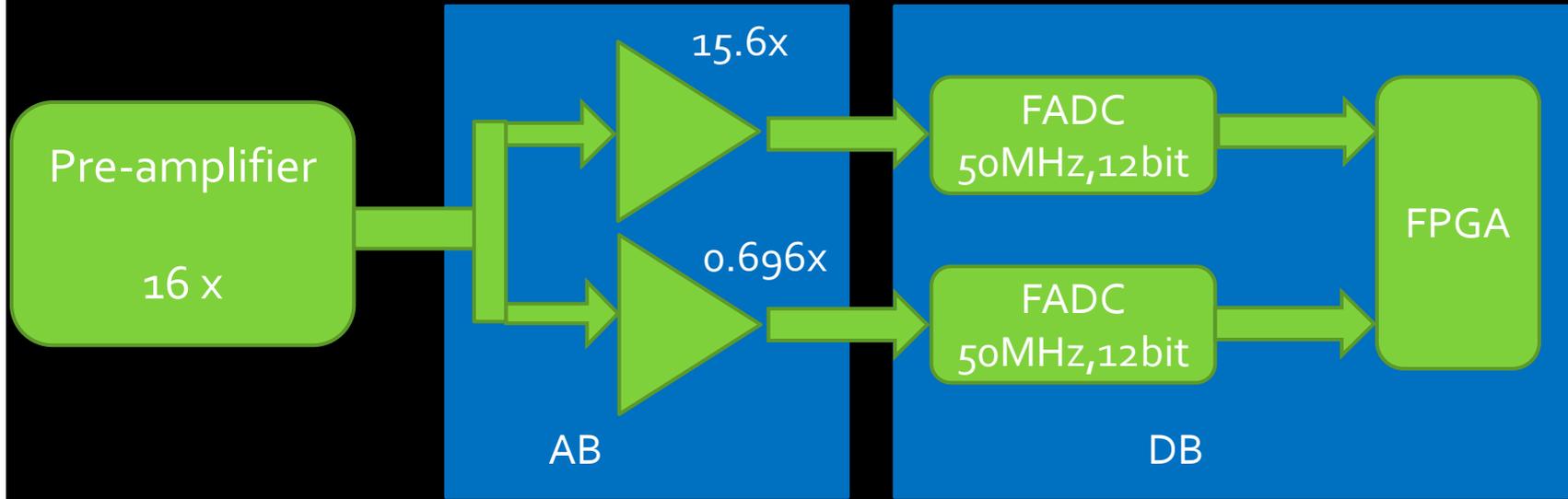
Stability of the Gain

Keep operating voltage stable



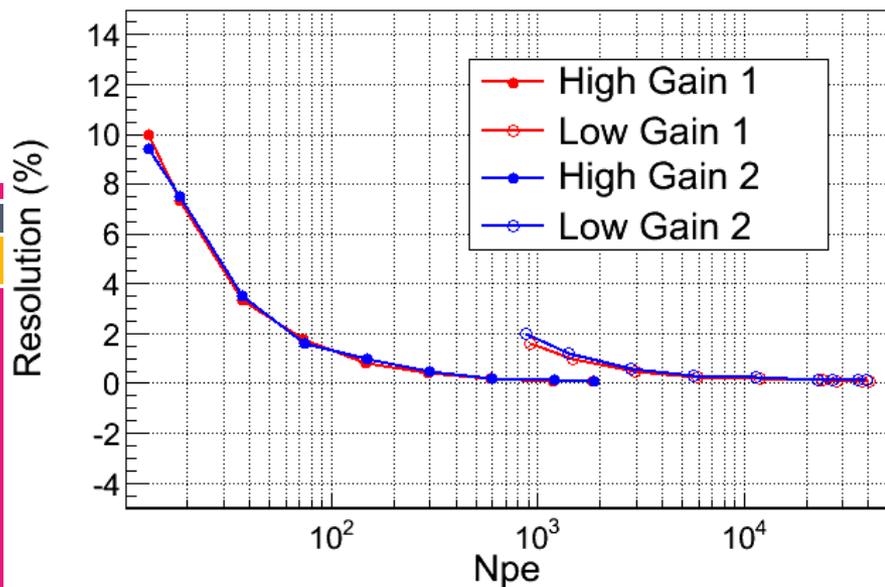
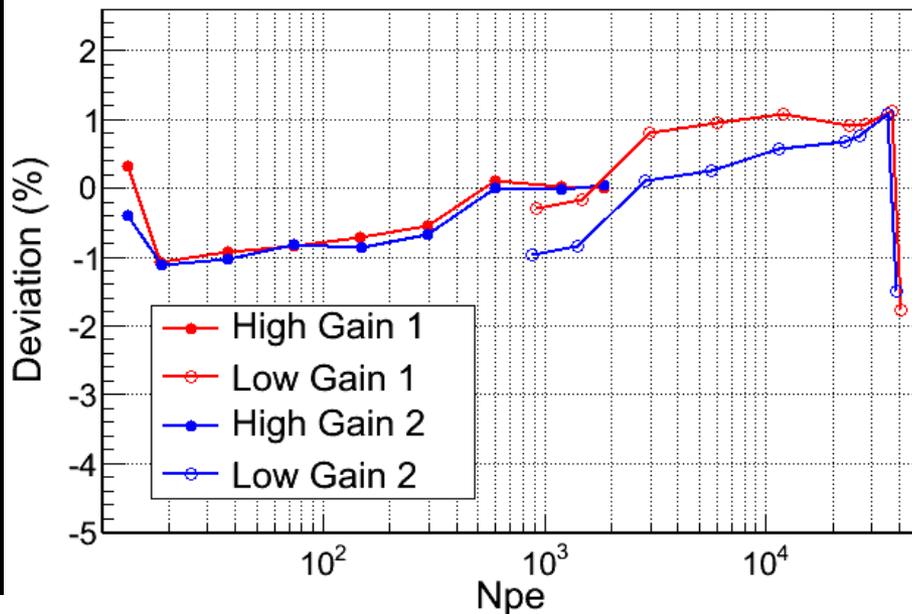
Duration of fluorescence signal could reach several μs

Design of Analog/Digital Board



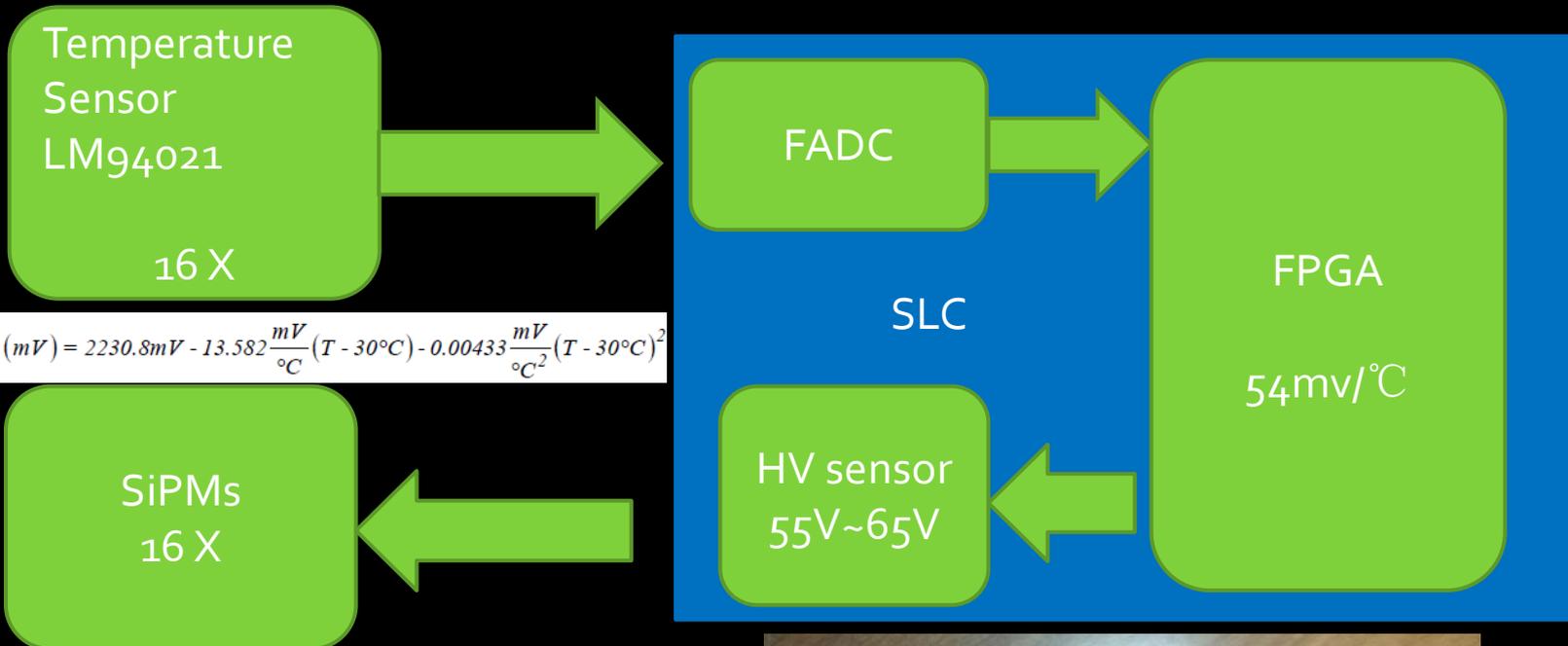
Test of AB/DB

Dynamic Range:
Deviation < $\pm 2\%$
10 pe ~ 3200pe

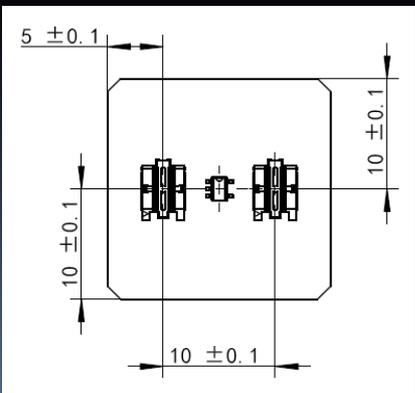


Resolution:
~10% @ 10pe
<2% @ >70pe

Design of Slow Control Board



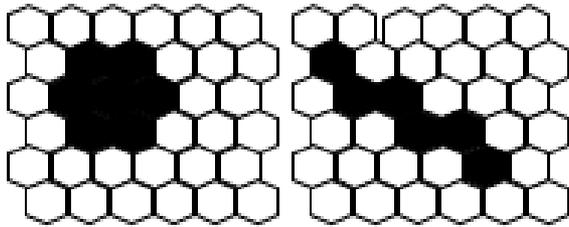
$$V_{TEMP}(mV) = 2230.8mV - 13.582 \frac{mV}{^{\circ}C}(T - 30^{\circ}C) - 0.00433 \frac{mV}{^{\circ}C^2}(T - 30^{\circ}C)^2$$



Trigger algorithm

- First level trigger: single channel trigger
 - Signal to noise ratio: $S/N > n$
 - Threshold varies with the intensity of the sky background light.
- Second level trigger: pattern recognition

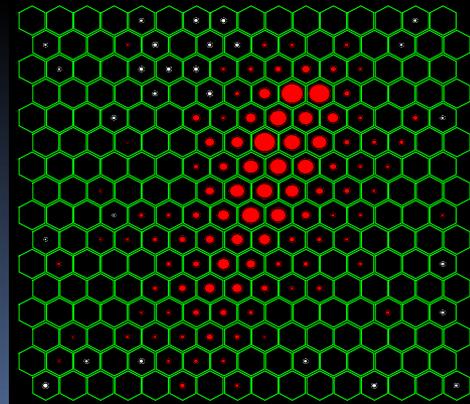
Patterns



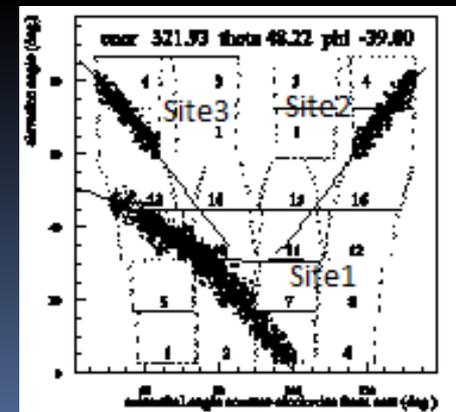
Round-shaped pattern

Line-shaped pattern

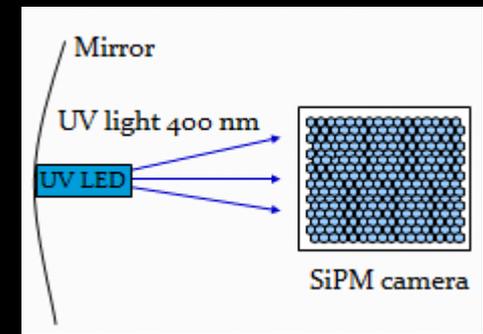
Cherenkov Event



Fluorescence Event



Gain monitor

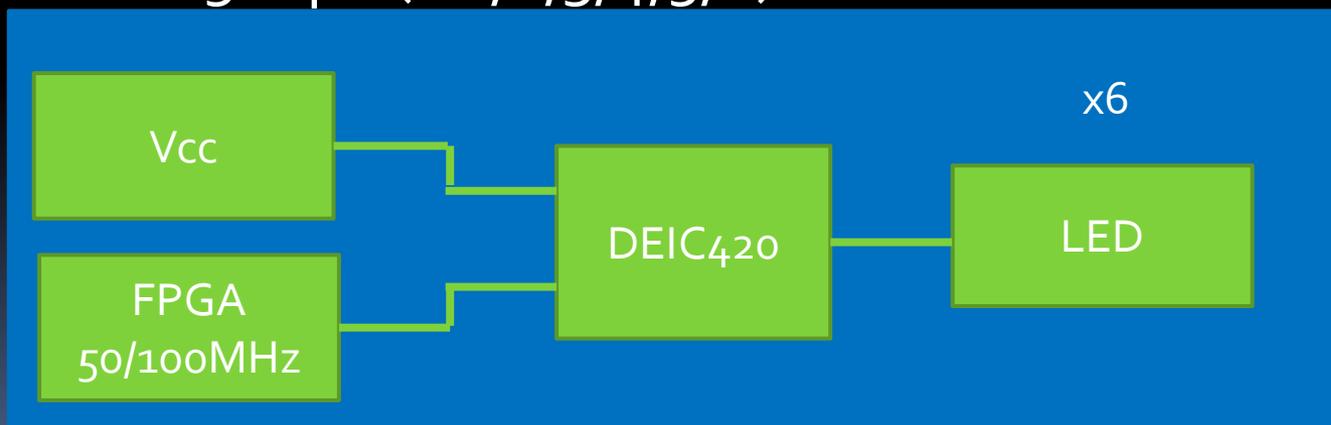
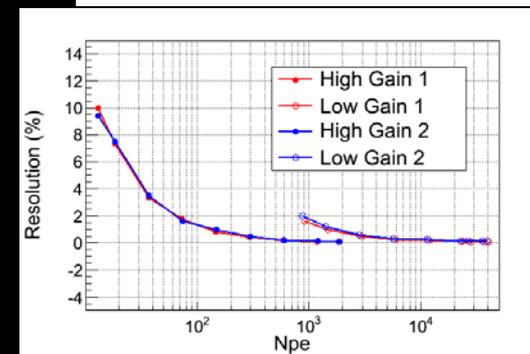
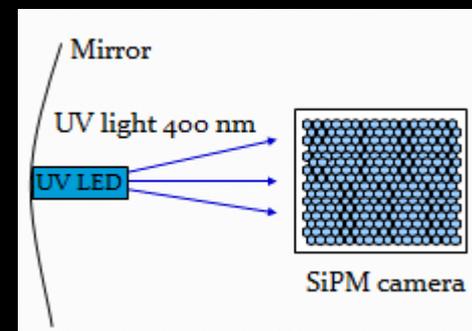


- The Gain of SiPM
 - The SiPM gain (break down voltage) is sensitive to the temperature.
 - The voltage drop on the R_0 varies with the intensity of the sky background light.
- Monitor the high gain and the low gain of the electronics.
- UV-LEDs configuration
 - Low Temperature Coefficient ($\sim 0.2\%$)
 - Pulse width < 20 ns

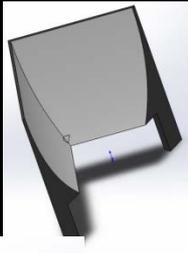
Gain monitor

➤ Point Light Source

- Light source: 12mm
- Focus distance: 2870mm
- Camera size: 800mm
- 3.88% lower at corner than center
- 500pe (x 1,2,3,4,5,6)



Winston Cone

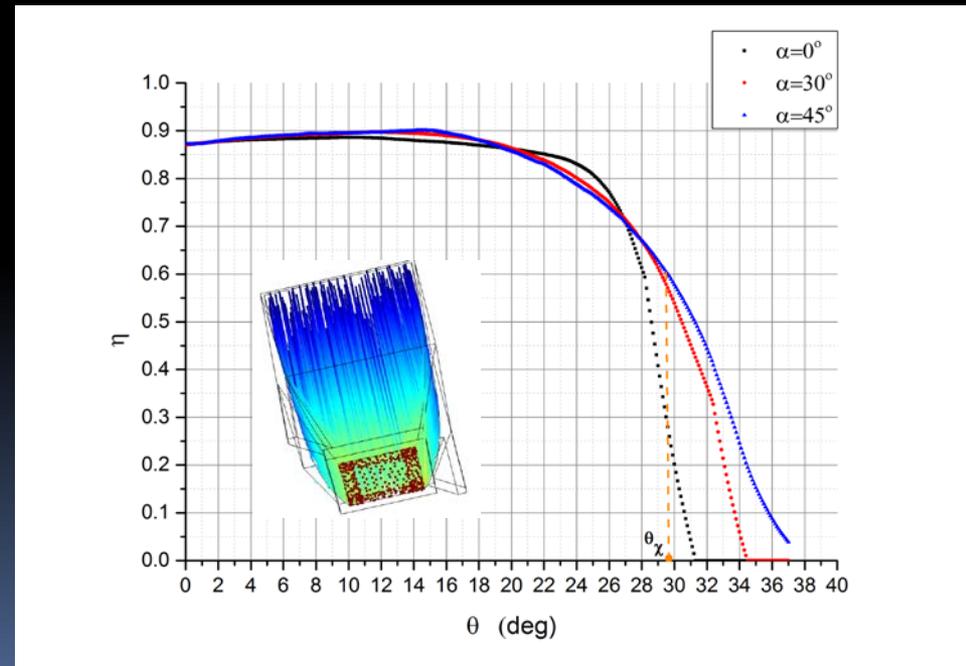
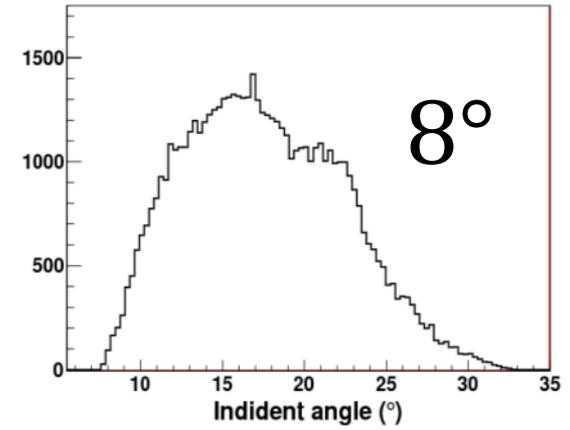
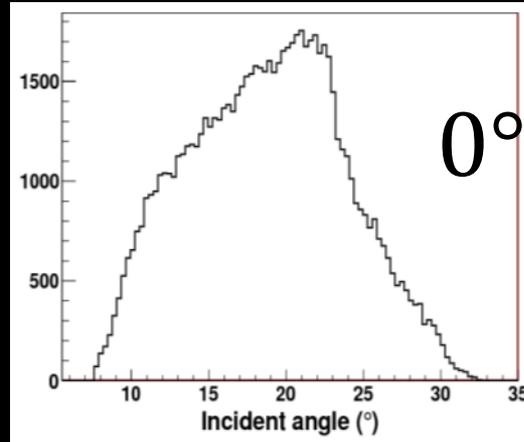
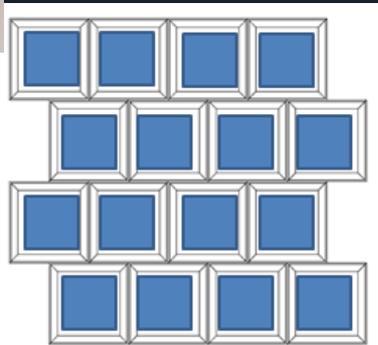
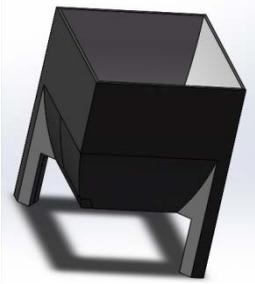


Pixel: 25.4mm

In: 24.4mm

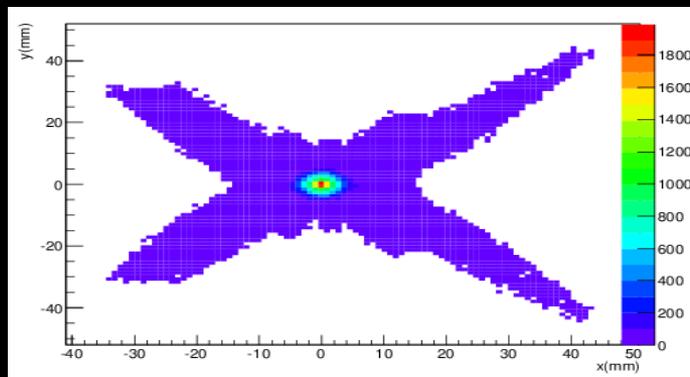
Out: 15mm

Height: 25.3mm

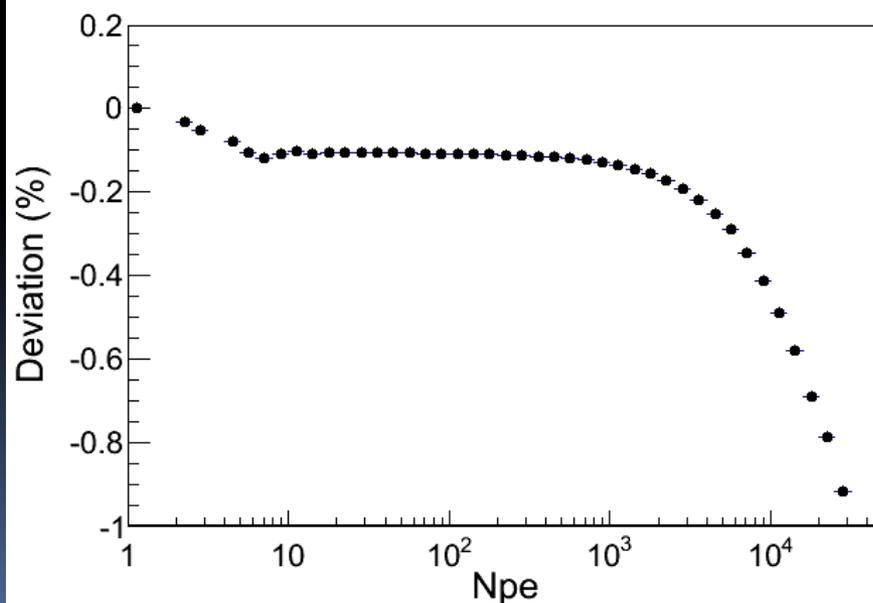
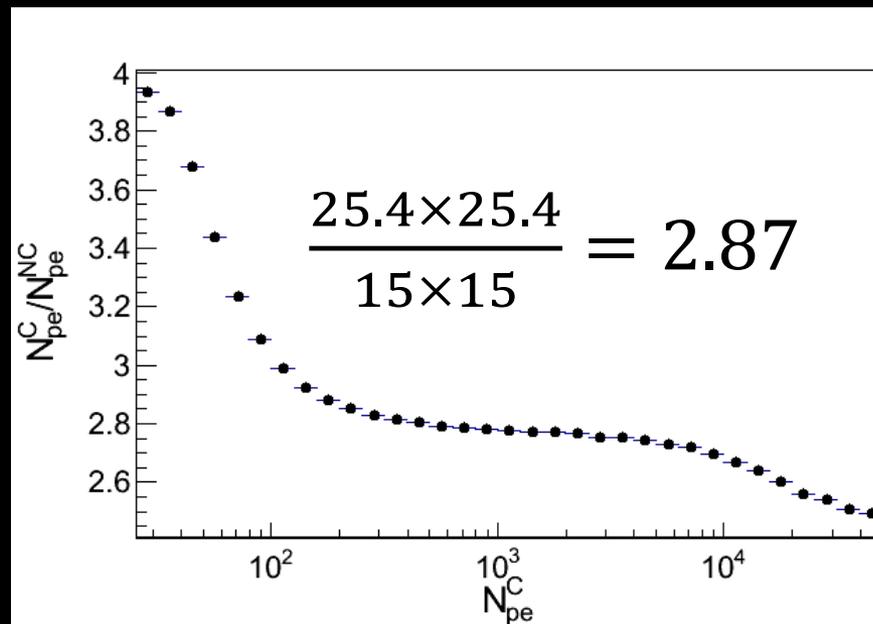
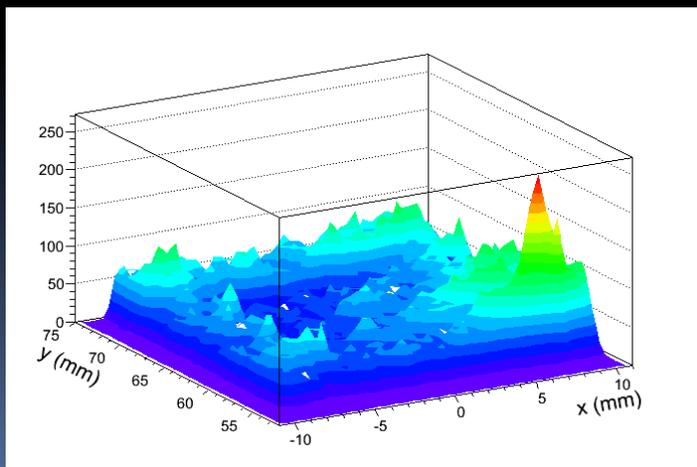


Simulation

Photons on focal plane



Photons on SiPM surface



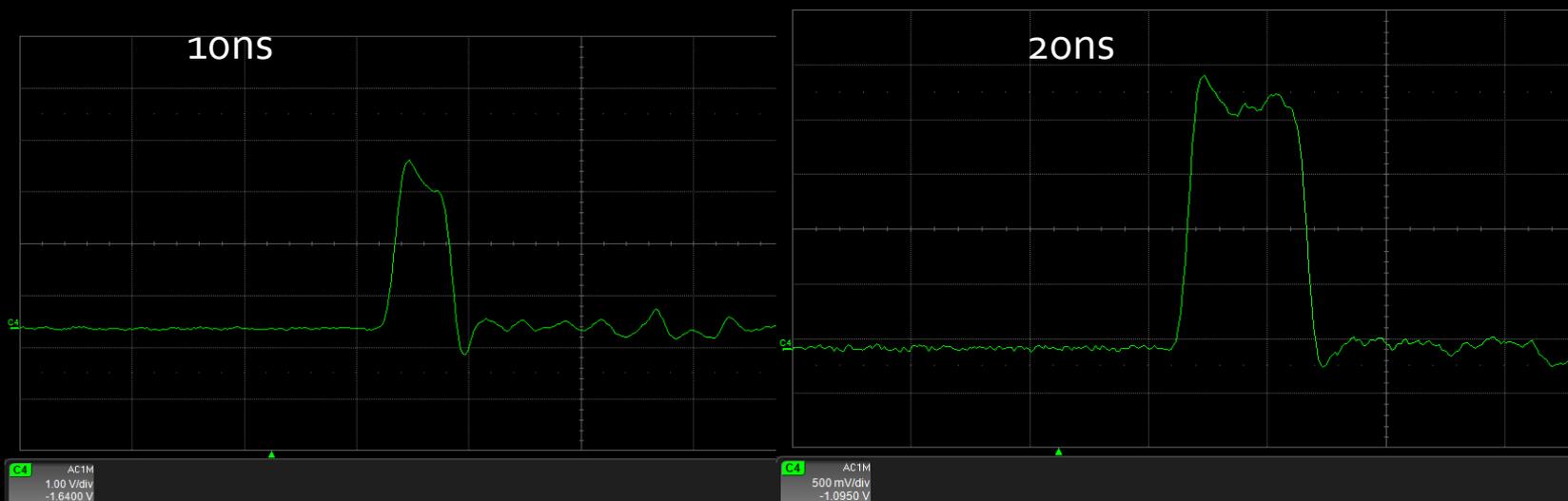
Summary

- Camera Design
 - We have designed a new SiPM
 - Pre-amplifier, AB, DB have been finished, more tests are undergoing
 - Slow Control Board is being developed
 - Winston cone is being tested
- Time schedule
 - First SiPM camera will be built before Jan. 2018;
 - 6 telescopes based on SiPM camera will be built and run before the end of 2018.
 - 16 telescopes will be run at 2020.

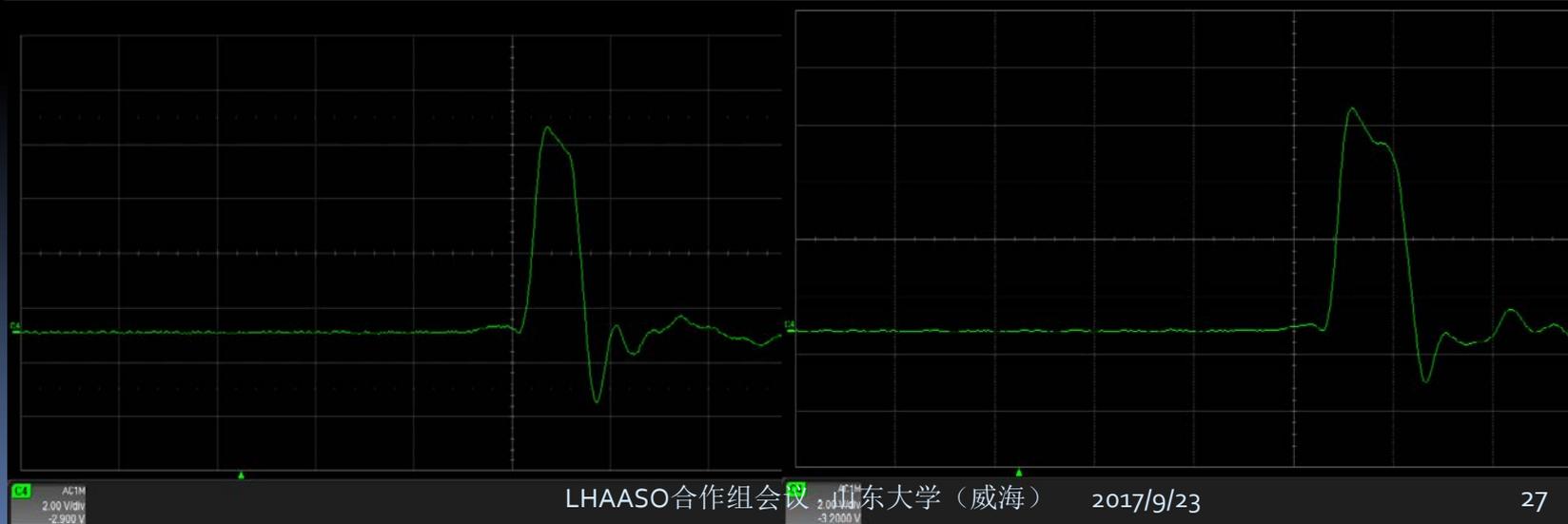


DEIC420 In/Out

In



Out



Signal to noise ratio

	SiPM	PMT (R7899)
Relative PDE/QE	29%@400 nm	16%@400 nm
Dark count rate @ threshold=0.5pe	5.4MHz	<1kHz
Sky background noise	~37 MHz	~21MHz
S/N Ratio	0.11Ns	0.087Ns

$$\frac{S}{\sqrt{N}} = \frac{N_s^{ph} \times PDE}{\sqrt{N_{BG}^{ph} \times PDE + N_{DCR}^{pe}}} \propto \frac{N_s^{ph}}{\sqrt{N_{BG}^{ph}}} \times \sqrt{PDE}$$